

SPECIFICATIONS T _J = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	40			V
V _{DS} Temperature Coefficient	ΔV _{DS} /T _J	I _D = 250 μA		40		mV/°C
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)} /T _J			- 4.6		
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	0.8		2.2	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 16 V			100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			1	μA
		V _{DS} = 40 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	20			A
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 10 V, I _D = 5 A		0.032	0.039	Ω
		V _{GS} = 4.5 V, I _D = 4 A		0.041	0.050	
Forward Transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 5 A		15		S
Dynamic ^a						
Input Capacitance	C _{iss}	V _{DS} = 20 V, V _{GS} = 0 V, f = 1 MHz		625		pF
Output Capacitance	C _{oss}			88		
Reverse Transfer Capacitance	C _{rss}			50		
Total Gate Charge	Q _g	V _{DS} = 20 V, V _{GS} = 10 V, I _D = 5 A		14.4	22	nC
Gate-Source Charge	Q _{gs}	V _{DS} = 20 V, V _{GS} = 4.5 V, I _D = 5 A		6.6	10	
Gate-Drain Charge	Q _{gd}			1.6		
				2.3		
Gate Resistance	R _g	f = 1 MHz		2.3	3.5	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = 20 V, R _L = 4 Ω I _D ≡ 5 A, V _{GEN} = 10 V, R _g = 1 Ω		9	15	ns
Rise Time	t _r			51	77	
Turn-Off Delay Time	t _{d(off)}			21	32	
Fall Time	t _f			6	10	
Turn-On Delay Time	t _{d(on)}	V _{DD} = 20 V, R _L = 4 Ω I _D ≡ 5 A, V _{GEN} = 4.5 V, R _g = 1 Ω		13	20	
Rise Time	t _r			85	128	
Turn-Off Delay Time	t _{d(off)}			17	26	
Fall Time	t _f			7	11	
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			2.5	A
Pulse Diode Forward Current ^a	I _{SM}				30	
Body Diode Voltage	V _{SD}	I _S = 1.7 A		0.79	1.2	V
Body Diode Reverse Recovery Time	t _{rr}	I _F = 1.7 A, di/dt = 100 A/μs, T _J = 25 °C		30	45	ns
Body Diode Reverse Recovery Charge	Q _{rr}			30	45	nC
Reverse Recovery Fall Time	t _a			17		ns
Reverse Recovery Rise Time	t _b			13		

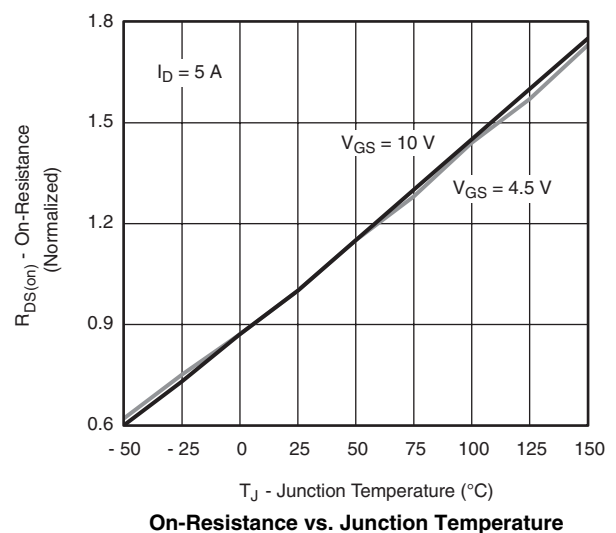
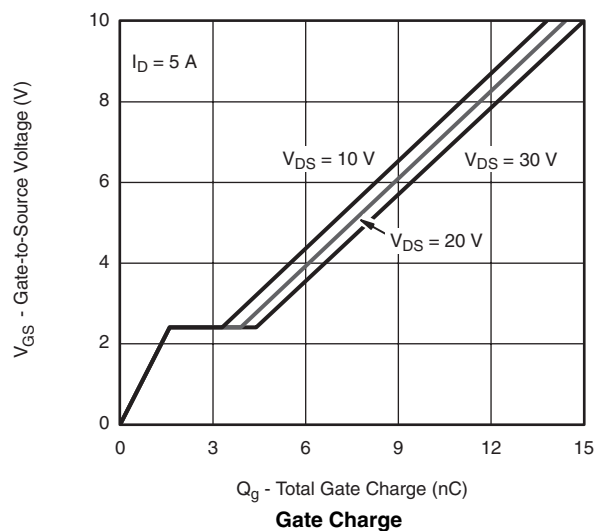
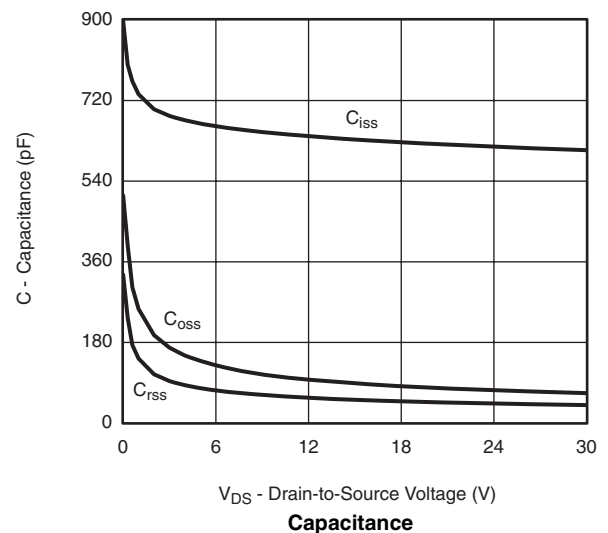
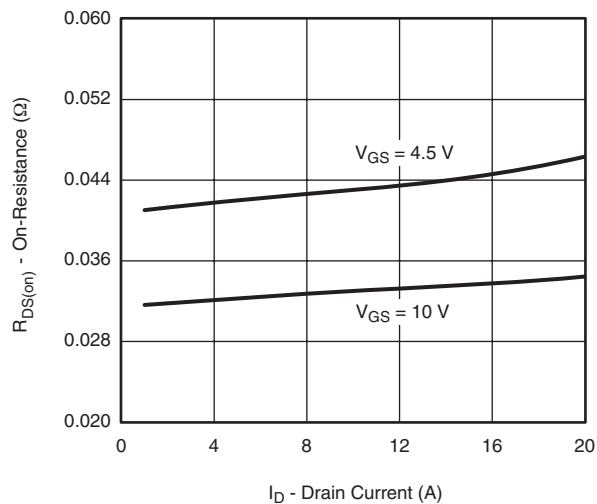
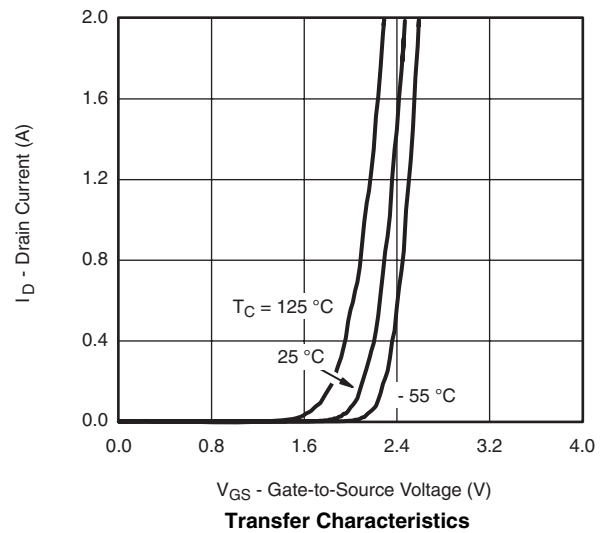
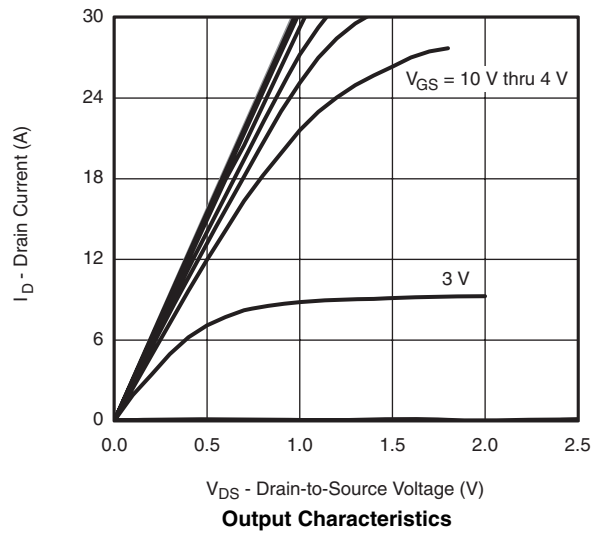
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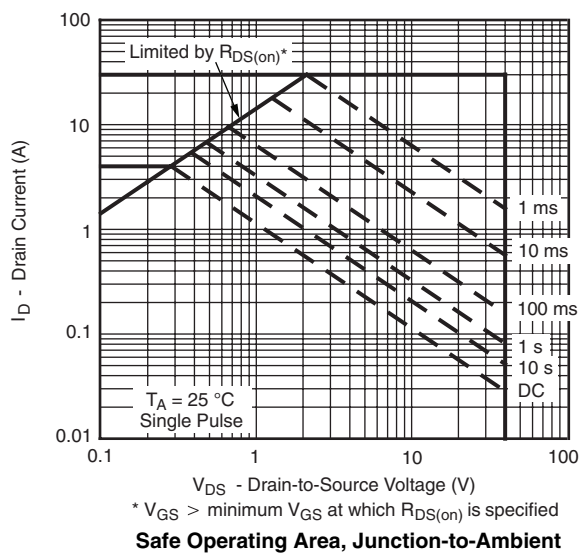
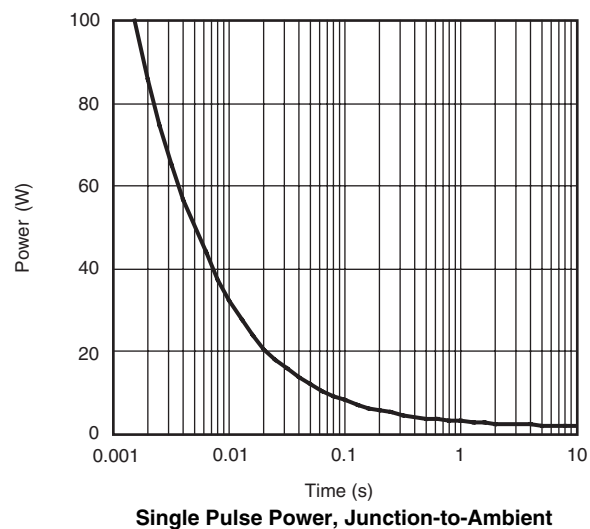
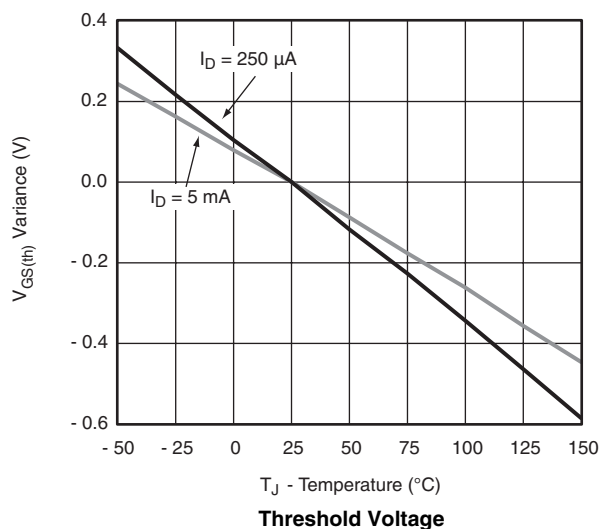
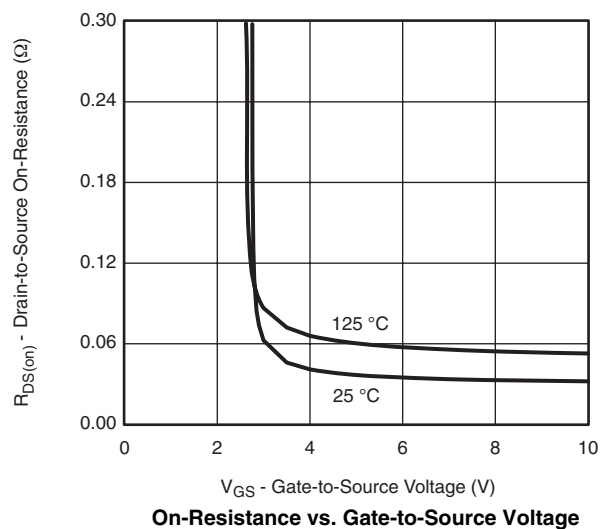
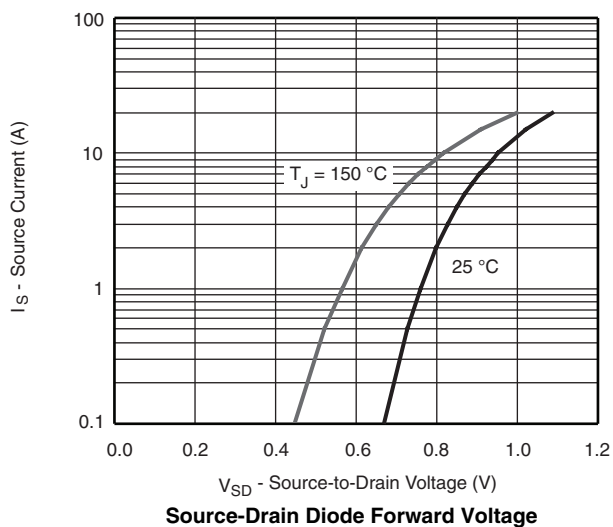
a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

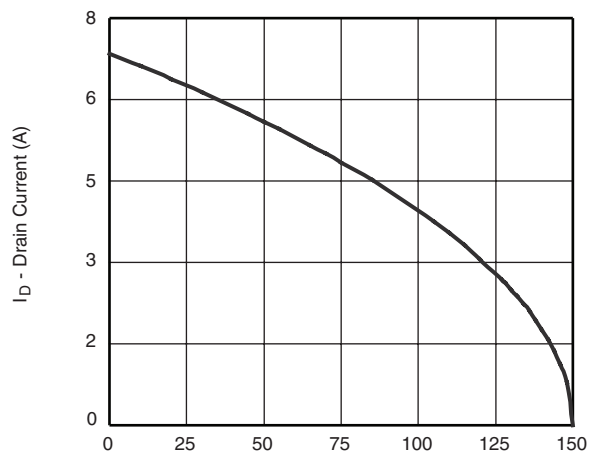
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

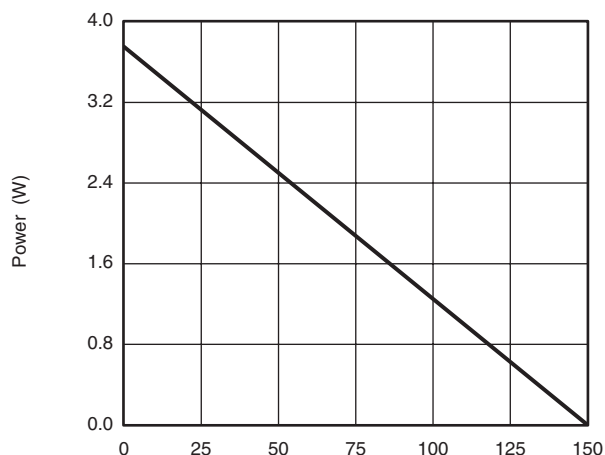


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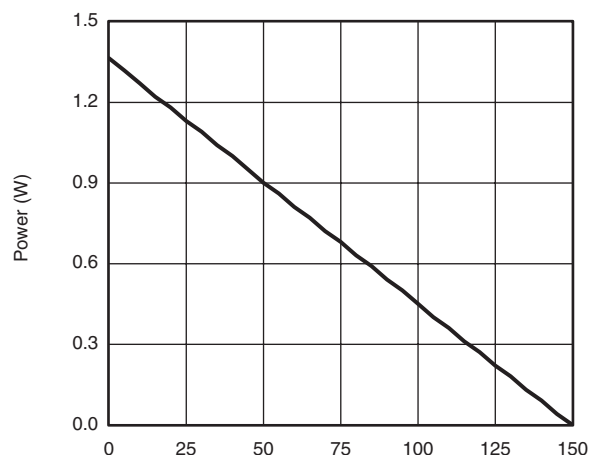
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T_C - Case Temperature (°C)
Current Derating*

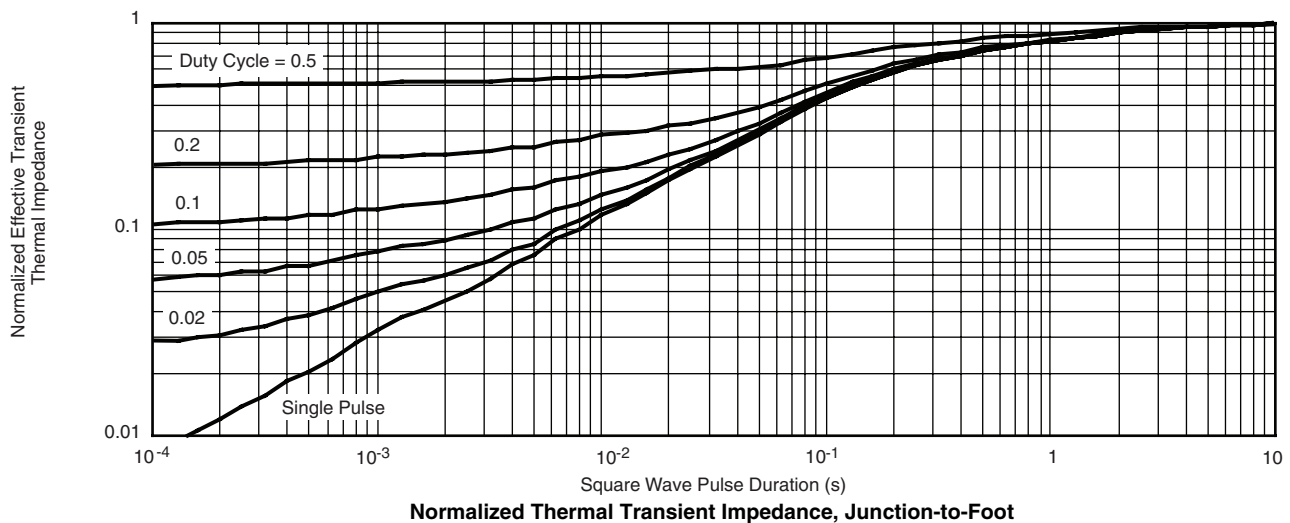
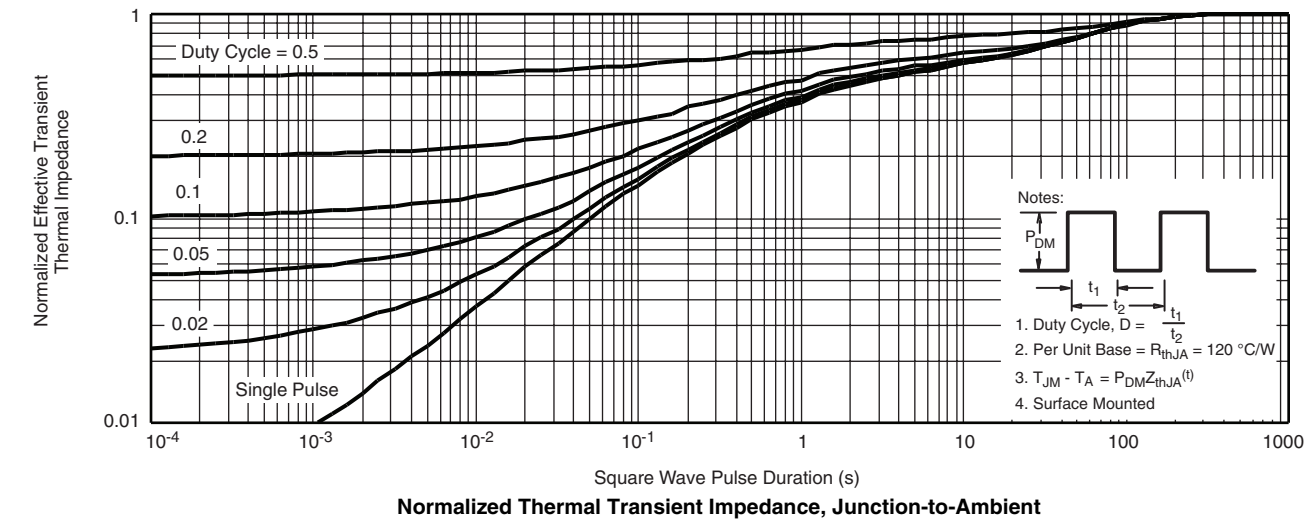


T_C - Case Temperature (°C)
Power Derating, Junction-to-Foot



T_A - Ambient Temperature (°C)
Power Derating, Junction-to-Ambient

* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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